

**SUPER FAST
GLASS PASSIVATED RECTIFIERS**

REVERSE VOLTAGE - **100 to 600** Volts
FORWARD CURRENT - **10** Amperes

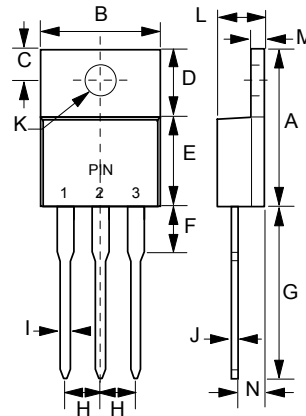
FEATURES

- Glass passivated chip
- Superfast switching time for high efficiency
- Low forward voltage drop and high current capability
- Low reverse leakage current
- High surge capacity
- Plastic package has UL flammability classification 94V-0

MECHANICAL DATA

- Case : TO-220AB molded plastic
- Polarity : As marked on the body
- Weight : 0.08 ounces, 2.24 grams
- Mounting position : Any
- Max. mounting torque = 0.5 N.m (5.1 Kgf.cm)

TO-220AB



TO-220AB		
DIM.	MIN.	MAX.
A	14.22	15.88
B	9.65	10.67
C	2.54	3.43
D	5.84	6.86
E	8.26	9.28
F	-	6.35
G	12.70	14.73
H	2.29	2.79
I	0.51	1.14
J	0.30	0.64
K	3.53 \varnothing	4.09 \varnothing
L	3.56	4.83
M	1.14	1.40
N	2.03	2.92

All Dimensions in millimeter

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	STPR 1010CT	STPR 1020CT	STPR 1030CT	STPR 1040CT	STPR 1050CT	STPR 1060CT	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	100	200	300	400	500	600	V
Maximum RMS Voltage	VRMS	70	140	210	280	350	420	V
Maximum DC Blocking Voltage	VDC	100	200	300	400	500	600	V
Maximum Average Forward Rectified Current @Tc=125°C	I(AV)	10						A
Non Repetitive Peak Forward Surge Current Per Diode Sinusoidal Tp=8.3ms	IFSM	55						A
Maximum forward Voltage Pulse Width =300us Duty cycle	VF	IF=5A@Tj =25°C 1.1 IF=5A@Tj =125°C 1.0 IF=10A@Tj =25°C 1.25 IF=10A@Tj =125°C 1.20		1.3 1.2 1.5 1.4		1.5 1.4 1.7 1.6		V
Maximum DC Reverse Current at Rated DC Blocking Voltage @Tj =25°C @Tj =100°C	IR	10 250						uA
Typical Junction Capacitance per element (Note 1)	CJ	80						pF
Maximum Reverse Recovery Time (Note 2)	TRR	30		35		50		ns
Typical Thermal Resistance	Rθ JC	4.0						°C/W
Operating and Storage Temperature Range	TJ,TSTG	-55 to +150						°C

NOTES : 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
2.Reverse Recovery Test Conditions:IF=0.5A,IR=1.0A,IRR 0.25A.

REV. 1, Aug-2007, KTGC10

FIG.1 - FORWARD CURRENT DERATING CURVE

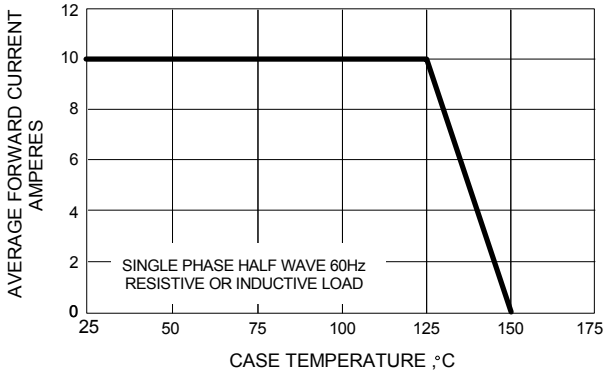


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

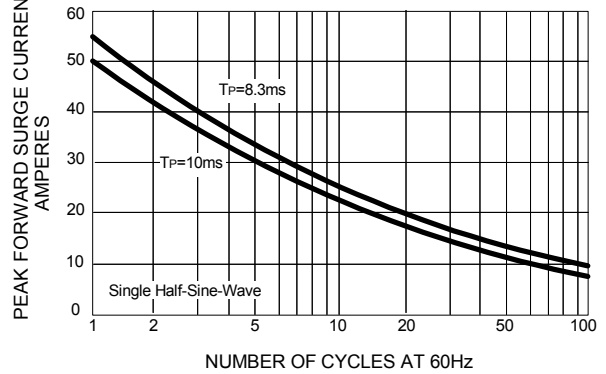


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

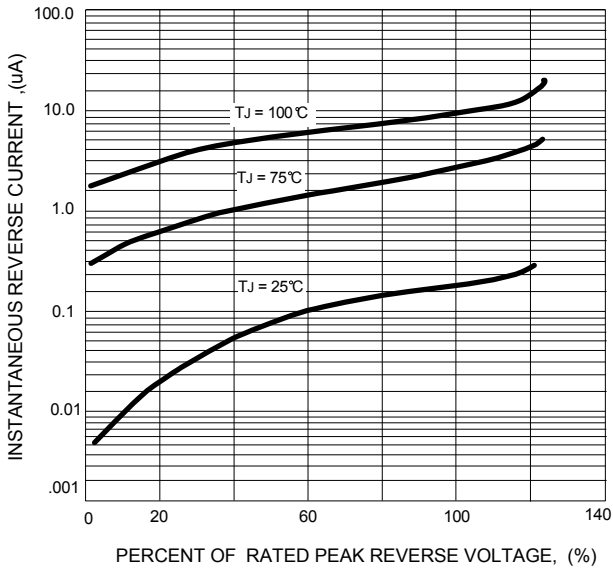


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

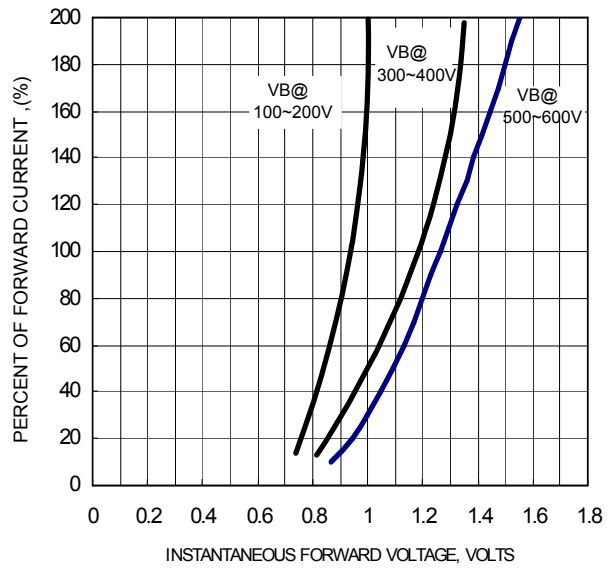


FIG.5 - TYPICAL JUNCTION CAPACITANCE

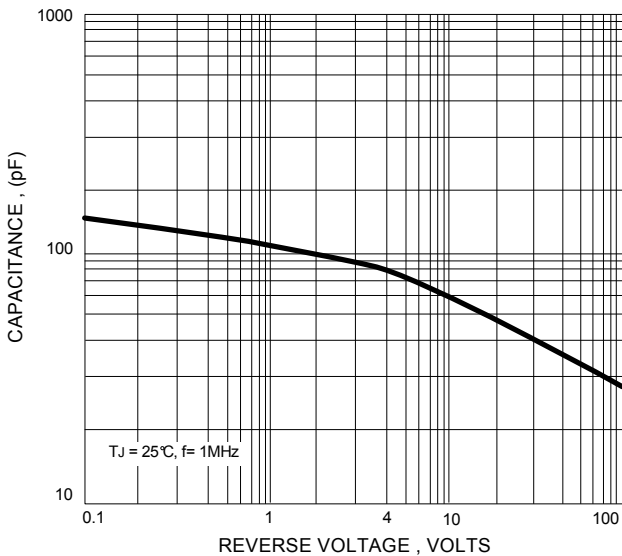


FIG.6 - MAXIMUM NON REPETITIVE SURGE PEAK FORWARD CURRENT VERSUS OVERLOAD DURATION PER DIODE

